

### 1000MHz 22dB Gain with GaAs Push-Pull Amplifier Module

## 1. Product profile

### 1.1 General description

High dynamic range power doubler amplifier module operating at a supply voltage of 24VDC in an SOT115J package, using a GaAs MMIC, matching with SMT transformers at input and output port, adding ESD and surge protective devices.

#### CAUTION



This device is sensitive to Electro Static Discharge (ESD). Therefore care should be taken during transport and handling.

### 1.2 Features and benefits

- n Excellent linearity
- n Low noise
- n Low return loss
- n Rugged construction
- n High reliability

### 1.3 Applications

- n CATV systems operating in the 40 MHz to 1000MHz frequency range.

### 1.4 Quick reference data

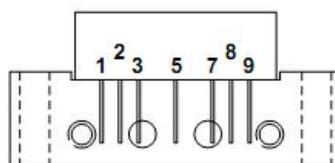
Bandwidth 40 MHz to 1000MHz;  $V_B = 24\text{ V}$ ;  $T_{mb} = 30\text{ }^\circ\text{C}$ ;  $Z_S = Z_L = 75\text{ }\Omega$

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$G_p$	power gain	$f = 50\text{ MHz}$	21.5	22.0	23.0	dB
		$f = 1000\text{MHz}$	22.5	-	-	dB
$I_{tot}$	total current	$V_B = 24\text{ V}$	240	260	280	mA

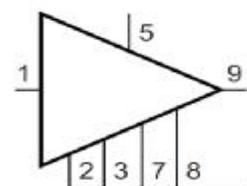
## 2. Pin information

Pin	Description
1	input
2	common
3	common
5	+ $V_B$
7	common
8	common
9	output

Simplified Outline



Graphic Symbol



## 3. Operating conditions

### 3.1 Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134) (TA = +25°C)

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V <sub>B</sub>	-	25	V
Input Voltage <sup>[1]</sup>	V <sub>i</sub>	-	60	dBmV
Operating Case Temperature	T <sub>c</sub>	-20	+90	°C
Storage Temperature	T <sub>stg</sub>	-40	+100	°C

[1] In case of single tone

### 3.2 Recommended operating conditions (Z<sub>S</sub> = Z<sub>L</sub> = 75 Ω)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Supply Voltage	V <sub>B</sub>		23.0	24.0	24.5	V
Operating Case Temperature	T <sub>c</sub>		-20	+30	+80	°C

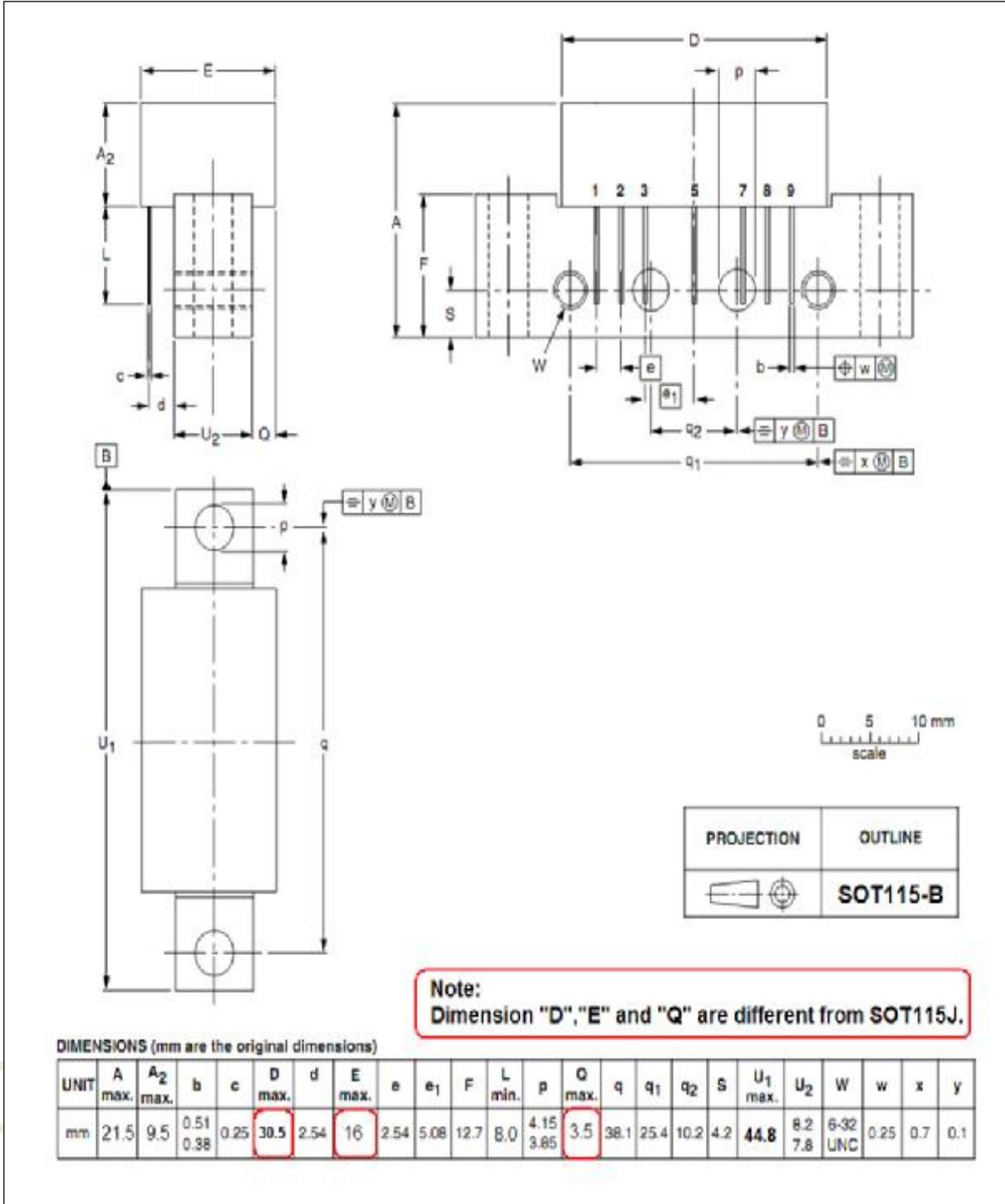
## 4. Electrical characteristics

(T<sub>c</sub> = 30±5°C, V<sub>B</sub> = 24 V, Z<sub>S</sub> = Z<sub>L</sub> = 75 Ω)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Power Gain	G <sub>p</sub>	f = 50 MHz	21.5	22.0	23.0	dB
Gain Slope	S <sub>L</sub>	f = 50 to 1000MHz	1.0	1.5	2.5	dB
Gain Flatness	FL	f = 50 to 1000MHz	-	-	±0.5	dB
Noise Figure	NF	f = 50 to 1000MHz	-	5.5	6.2	dB
Operating Current	I <sub>B</sub>	V <sub>B</sub> =24VDC, RF OFF	240	260	280	mA
Composite Triple Beat	CTB		-	-65	-	dB
Cross Modulation	XM	98 channels, V <sub>O</sub> = 44dBmV at 743.25 MHz, flat output level across the band	-	-62	-	dB
Composite 2nd Order Beat	CSO		-	-66	-	dB
Input Return Loss	S <sub>11</sub>	f = 40 to 550MHz	18	-	-	dB
		f = 550 to 1000MHz	16	-	-	dB
Output Return Loss	S <sub>22</sub>	f = 40 to 550MHz	16	-	-	dB
		f = 550 to 1000MHz	16	-	-	dB

5. Package outline

Rectangular single-ended package; aluminum flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads.



UNIT: mm

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